

MBRF1035CT - MBRF10150CT



Isolated 10.0 AMPS. Schottky Barrier Rectifiers **ITO-220AB**

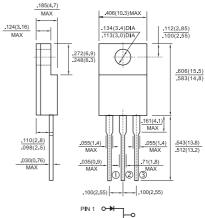


Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- Cases: ITO-220AB molded plastic
- Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- ♦ Polarity: As marked
- ✧ Mounting position: Any
- Mounting position: Any Mounting torque: 5 in. lbs. max Weight: 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 1035 CT	MBRF 1045 CT	MBRF 1050 CT	MBRF 1060 CT	MBRF 1090 CT		MBRF 10150 CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	150	V
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	105	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	150	V
Maximum Average Forward Rectified Current at T _C =133°C	I _(AV)	10							Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=133°C	I _{FRM}	RM 10.0							Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	I _{FSM} 120							Α
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	I _{RRM} 0.5							Α
Maximum Instantaneous Forward Voltage at (Note 2)	V _F	0. 0.	70 57 80 67	0. 0.	80 65 90 75	0. 0.	85 75 95 85	0.88 0.78 0.98 0.88	٧
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @Tc=25 °C @Tc=125 °C	I _R	0.1 15 10 5.0					mA mA		
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000						V/uS	
RMS Isolation Voltage (t=1.0 second, R.H. \leq 30%, T _A =25 °C) (Note 4) (Note 5) (Note 6)	V _{ISO}	4500 3500 1500							V
Typical Thermal Resistance Per Leg (Note3)	R _θ JC	3.5							°C/W
Operating Junction Temperature Range	TJ	-65 to +150							°C
Storage Temperature Range	Tstg	-65 to +150							°C

1. 2.0 us Pulse Width, f=1.0 KHz 2. Pulse 3. Thermal Resistance from Junction to Case Per Leg. 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle Notes:

- 4. Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.
 5. Clip mounting (on case), where leads do overlap heatsink.
 6. Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")



RATINGS AND CHARACTERISTIC CURVES (MBRF1035CT THRU MBRF10150CT)

